NSN 5961-01-331-3189

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Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-331-3189 **Inclosure Material:** Glass **Overall Length:** 1.246 inches **Terminal Length:** 0.446 inches **Overall Height:** 0.155 inches **Overall Width:** 0.380 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-202 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 600.0 repetitive peak reverse voltage and 720.0 nonrepetitive peak reverse voltage and 600.0 repetitive peak off-state voltage **Current Rating Per Characteristic:** 3.15 amperes forward current, total rms horsepower metric and 2.00 amperes drain current universal and 20.00 amperes forward current, total rms watts **Power Rating Per Characteristic:** 0.5 watts small-signal input power, common-collector blank and 0.1 watts any acceptable universal **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: